## NSN 5961-01-470-7965

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End	Λn	alica	tion:
⊏Hu	Api	ullua	tion:

Ari 23338

## **Special Features:**

Manufacturer nomenclature tuning varactor; silicon abrupt junction devices offer highest q and lowest resistance available in 30 volt tuning diodes; silicon dioxide passivation process assures greater stability, reliability and low leakage currents at higher temperatures; used for narrow and wide band tuning through x-band; operating temperature -55 to +150 degrees c

Shelf Life:

N/a

**Unit Of Measure:** 

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**Demilitarization:** 

Yes - demil/mli

Fiig:

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